Organic Electronics

Next Generation Displays Flexible Electronics Wearables

AIXTRON Investor Presentation

Opto & Power Electronics

Next Generation Displays SSL Adoption · UV-C Renewable Energy Power Management E-Mobility · Connectivity Our technology.
Your future.

Memory & Logic

High Performance Computing Memory / Big Data Sensors - Smart Devices

Graphene & Nanomaterials

Flexible Electronics Sensors · Energy Storage High Performance Computing Composites

IR Presentation – 9M/2017

(FSE: AIXA, ISIN DE000A0WMPJ6)

RIXTRON

Disclaimer 2

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ABOUT AIXTRON

Our Vision

Technology. Materials. Performance.

Technology.

We are the **recognized technology leader** in complex material deposition.

Materials.

We **enable our customers** to
successfully shape the
markets of the future,
exploiting the potential
offered by **new materials**.

Performance.

We deliver the performance driving economic success through our expertise, our employees and the quality of our products.



ABOUT AIXTRON

Who we are



- Headquarters based in Herzogenrath, Germany
- Worldwide presence with 13 sales/representatives offices and production facilities
- Company founded in 1983 over 30 years of experience
- ~ 680 employees

- Technology leader in deposition systems
- More than 3,000 deposition systems delivered all over the world
- State of the art R&D center and demo facilities



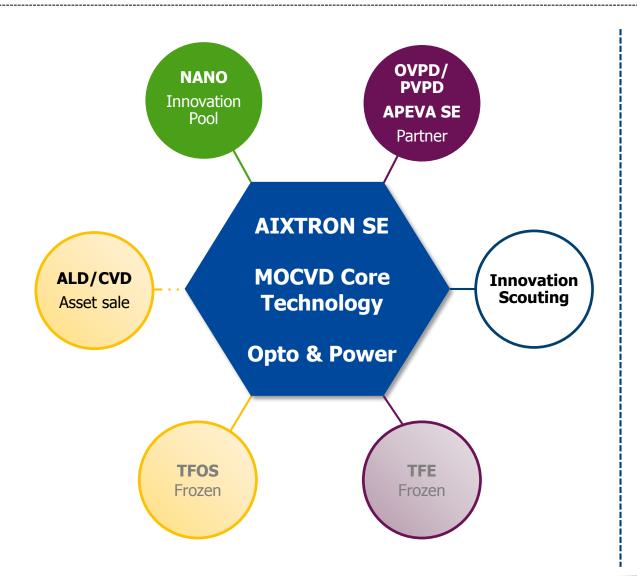
ABOUT AIXTRON

Global Presence





Technology Portfolio – Strategy



Executing Strategic Plans:

- ✓ Partner: APEVA / OLED Deposition
 - Established APEVA SE as AIXTRON subsidiary; Joint Venture discussions in progress
- ✓ Freezing R&D: TFOS & TFE
 - Q1/2017: freezing III-V on Silicon (TFOS) R&D activities
 - Q2/2017: freezing Thin Film Encapsulation (TFE) R&D activities
- ✓ Asset Sale: Memory Product Line
 - Sale of ALD/CVD Memory Product line to Eugene Technology in South Korea expected to close in 2017



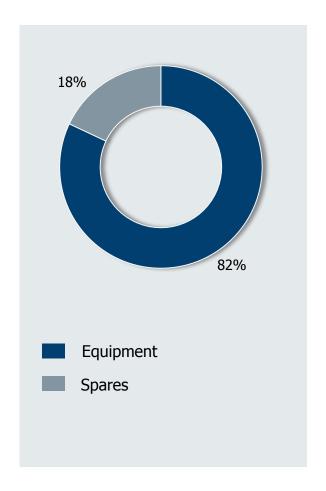
Technology Portfolio



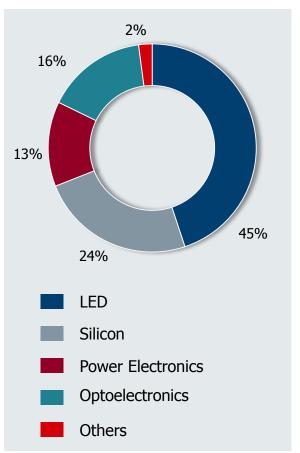


Revenue Analysis*

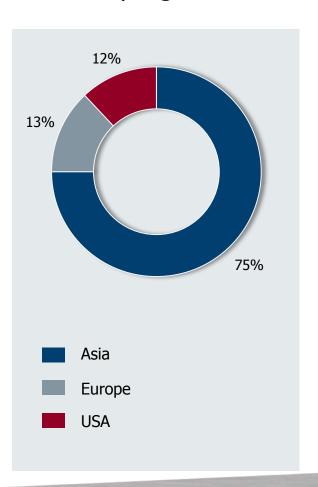
9M/2017: by equipment & spares



9M/2017: by end application (equipment only)



9M/2017: by region





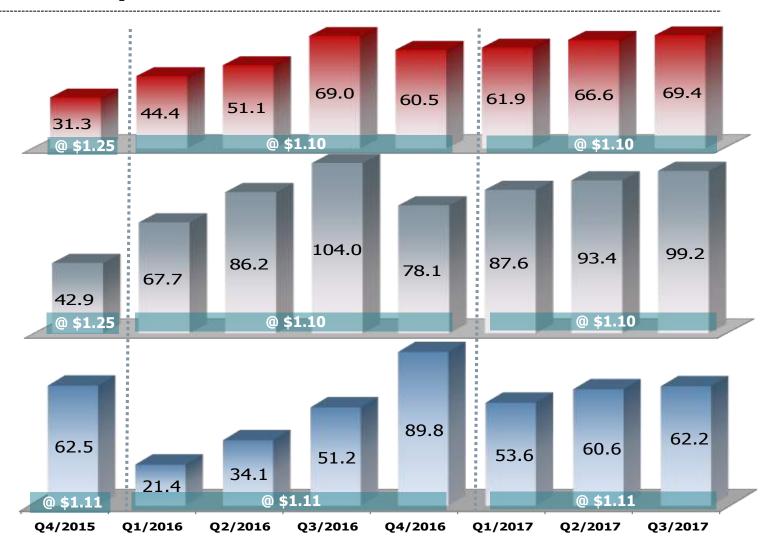
24 - Month Business Development

(€ million)

Order Intake (incl. equipment, service, spare parts)

Order Backlog (equipment only)

Total Revenues (incl. equipment, service, spare parts)



USD order intake and backlog were recorded at the prevailing budget rate (2017: \$1.10/€) USD revenues were converted at the actual period average FX rate (9M/2017: \$1.11/€)



Consolidated Income Statement*

* Rounded figures; may not add up **Q3/17 adjusted vs Q2/17 adjusted

(C million)	Q3/17		Q2/17			+/-	
(€ million)	Adjusted	Adjustment	Actual	Adjusted	Restructuring	Actual	%**
Revenues	57.6	-4.6	62.2	60.6		60.6	-5
Cost of sales	37.5		37.5	45.9		45.9	-18
Gross profit	20.1	-4.6	24.7	16.0	1.3	14.7	26
%	<i>35</i>		40	26		24	9рр
Selling expenses	2.7		2.7	2.7		2.7	0
General & admin expenses	3.7	-1.4	5.2	3.8	-1.3	5.1	3
R&D	12.8		12.8	14.8	-5.0	19.8	-14
Net other operating income & expenses	-0.5		-0.5	-1.6		-1.6	-69
EBIT	1.4	-3.2	4.6	-3.6	7.7	-11.3	139
%	2		7	-6		-19	8рр
Net result	1.1	-3.2	4.3	-3.7	7.7	-11.4	130
%	2		7	-6		-19	8рр



Consolidated Income Statement*

* Rounded figures; may not add up **9M/17 adjusted vs 9M/16 actual

(€ million)	9M/17			9M/16	+/-	
(E IIIIIIOII)	Adjusted	Adjusted	Actual	Actual	%**	
Revenues	171.7	-4.6	176.3	106.6	61	
Cost of sales	121.0		123.3	79.7	52	
Gross profit	50.8	-2.2	53.0	26.9	89	
%	30		30	<i>25</i>	5 pp	
Selling expenses	7.9		7.9	9.0	-12	
General & admin expenses	11.6	-2.9	14.5	12.1	-4	
R&D	41.6	-10.6	52.3	39.6	5	
Net other operating income & expenses	-2.2		-2.2	-4.5	-51	
EBIT	-8.2	11.3	-19.5	-29.3	72	
%	<i>-5</i>		-11	-27	22 pp	
Net result	-9.3	11.3	-20.6	-30.4	69	
%	-5		-12	-28	23 pp	



Balance Sheet*

(€ million)	30/09/17	30/06/17	31/12/16
Property, plant & equipment	64.0	65.3	74.2
Goodwill	71.1	68.7	74.6
Other intangible assets	1.8	1.5	5.4
Others	1.9	2.1	2.4
Non-current assets	138.8	137.5	156.5
Inventories	40.2	36.4	54.2
Trade receivables	21.1	22.0	60.2
Others	4.8	6.0	5.3
Assets classified as held for sale	15.4	16.0	0.0
Cash & Cash Deposits	203.9	197.1	160.1
Current Assets	285.3	277.6	279.7
Shareholders' equity	342.2	339.8	369.7
Non-current liabilities	1.7	2.5	4.2
Trade payables	13.1	13.9	14.6
Advance payments from customers	41.7	33.6	26.1
Others	25.3	25.3	21.6
Current liabilities	80.2	72.7	62.3
Balance Sheet total	424.1	415.0	436.2



Consolidated Statement of Cash Flows*

(€ million)				
(& ITIIIIOIT)	9M/17	9M/16	Q3/17	Q2/17
Net Result	-20.6	-30.4	4.3	-11.4
Adjust for				
Non Cash Items	16.8	9.8	2.6	6.8
Changes in Working Capital	60.4	-14.5	6.3	13.3
Cash Flow from Operating Activities	56.5	-35.0	13.2	8.7
Capital Expenditures	-8.0	-3.0	-5.0	-1.7
FX effects / Other	-4.7	-7.9	-1.4	-3.6
Total Cash Flow	43.8	-45.9	6.8	3.5
Cash & Deposits	203.9	163.5	203.9	197.1



FUTURE MARKETS 14

Market Prospects

Short-Term

 Increasing emergence of compound semiconductor based laser devices such as VCSELs for sensors in automotive and mobile applications.

- Increasing emergence of compound semiconductor based laser devices for ultrafast Telecom and Datacom infrastructure and data center applications.
- Increasing adoption of LEDs and specialty LEDs (in particular Red-Orange-Yellow, IR or UV) for Sensor, Fine Pitch Display and other applications.
- Increased emergence of wide band gap SiC based devices for energy efficient power management in automotive, consumer electronics and mobile applications.

Mid- to Long-Term

- Increased emergence of wide band gap GaN based devices for energy efficient power management and communications in automotive, consumer electronics and mobile applications.
- Increasing emergence of compound semiconductor based sensor devices for autonomous driving.
- Development of new wide band gap applications such as RF and System-on-Chip with integrated power management.
- Progress in the development of large area OLED displays requiring efficient deposition technologies such as OVPD.
- Increased development activity for specialized compound solar cell applications.
- Development of applications using Carbon Nanostructures (Carbon Nanotubes, Carbon Nanowires, Graphene, 2D-Materials).
- Development of alternative LED applications such as Visual Light Communication technology or Micro-LED Displays.



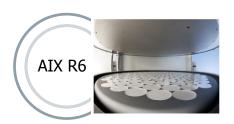
AIXTRON – Enabling Emerging Global Mega Trends

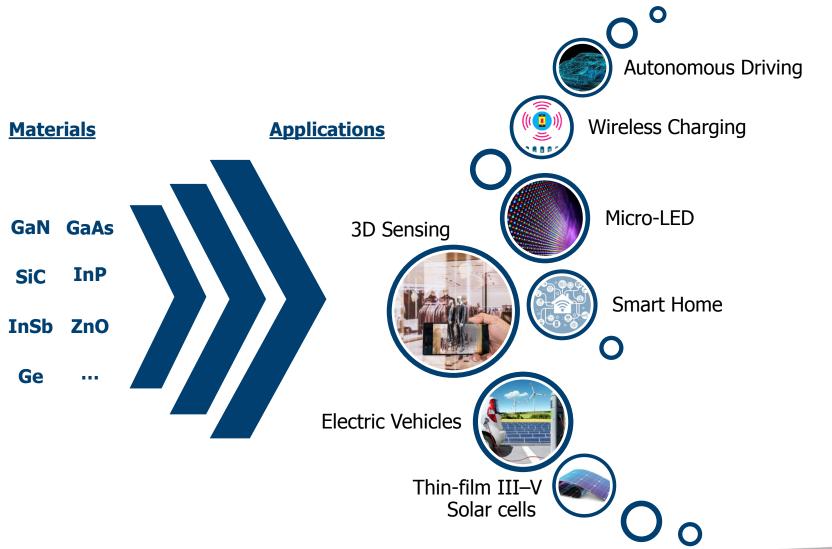














Application: Short Term – Compound Semis in Next-Gen CE

Source: Gartner; Credit Suisse, Deutsche Bank, Stifel

AIXTRON Enables GaAs Applications

RF Switches

RF Power transistors

HMIC Pin diode

MMIC

3D gesture sensors

Base Station for 3G / 4G

Logic processor

AIXTRON also in...

OLED Flexible Display **3D NAND**

1X DRAM

CNT based LiB

energy solution

Base station for 5G

MMIC

Fast charger

Wireless PAs

Noise cancelation

Camera Flash

Iris scan

Proximity sensor

Camera autofocus

Environmental scan

HDMI interconnects

Body functions

Night vision camera

Displays

Wireless charger

Pulsed power transistor

GaN ICs

AIXTRON Enables GaN Applications

Potential CE markets (2017e) ~3bn units

Smartphones: 1.55 bn units 0.18 bn units Laptops:

Tablets:

0.3 bn units

Smartwatches: 0.1 bn units Wearables: 0.3 bn units TV: 0.25 bn units Others (DSC, Game consoles): 0.1bn

Customer profiles:

- Fragmented and global
- IDMs, PDM, foundries and start ups
- GaN MOCVD: 100+ players with epi capability
- GaAs MOCVD: 60+ players with epi capability
- CNT PFCVD: shift toward commercial customers



Application: Mid Term – Compound Semis in Connected E-Vehicles

AIXTRON Enables GaAs Applications

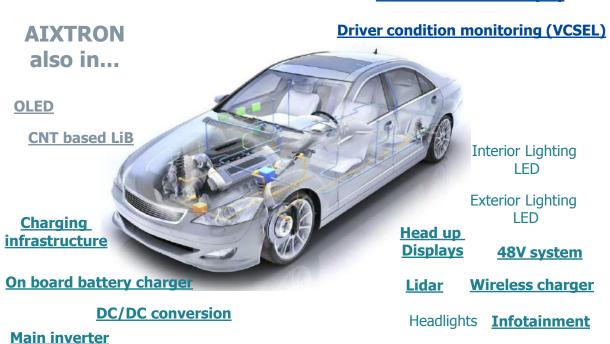
Vehicle speed sensing (IR)

Night vision IR Emergen

Emergency break assist (IR)

Adaptive cruise control (IR)

Pedestrian detection (IR)



AIXTRON Enables GaN Applications

Source: Gartner; Baader, Bernstein, Deutsche Bank, Stifel

Potential EV, BEV and PHEV~ 4m units in 2020e

- Power Semiconductor content per car internal combustion engine: \$50
- Power Semiconductor content per car electrical vehicle: \$350

Potential ADAS

~ 25m units in 2019e

- Semiconductor content partially automated: sub \$100 per car
- Semiconductor content fully automated: \$580 per car

Customer profiles:

- Fragmented and global
- IDMs, PDM, foundries and start ups
- GaN MOCVD: 100+ players with epi capability
- GaAs MOCVD: 60+ players with epi capability
- CNT PECVD: shift toward commercial customers



AIXTRON Enables SiC

Applications

Application: Long Term – Compound Semis in Smart Homes

AIXTRON also in... AIXTRON Enables GaAs Applications

OLED

CNT based LiB

Night vision IR

Terrestrial CPV

FTTH

3D gesture sensors

Motion sensors

Environmental sensors

Fast charger

5G Home Internet

Smart Lighting I FD

Wireless PAs

wearables

LiDAR Med-Tech AR Gaming

Wireless charger

AIXTRON Enables SiC Applications

Charging

infrastructure

Main inverter

AIXTRON Enables GaN Applications

Infotainment

Smart homes: Self-sufficient, environmentally friendly and

Source: Gartner; Credit Suisse, Deutsche Bank, Stifel

connected

Smart sensing: motion, environmental sensors, microphones

Processing: low power, high performance, microcontroller

Connectivity: Sub-GHz, Bluetooth, WiFi

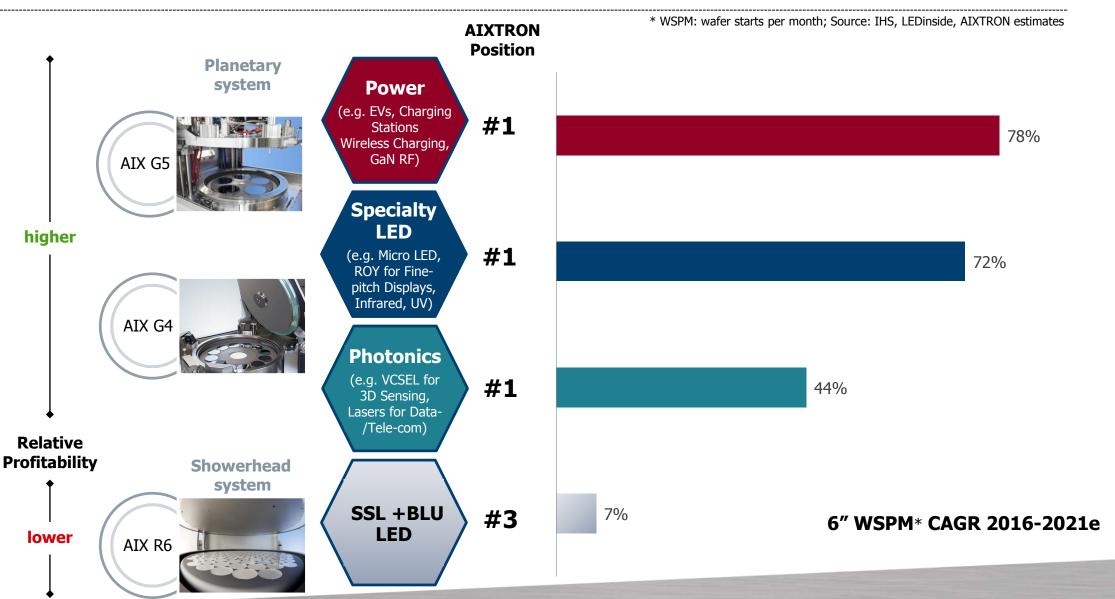
Energy management: digital power, energy harvesting

Applications:

 appliances, home control, household robots, smart lighting, home multimedia, smart door locks, EV chargers, smart meters, improved security

DC/DC conversion

AIXTRON Opto & Power – Positioned for Profitable Growth





Volume segment

Niche segment

Overview: GaN/SiC as Wide Band Gap (WBG) Power Electronics

Consumer Electronics & IT Automotive Industrial Energy Power Management Power Switching 30V 600V 1.2 kV ≥2kV • UPS Infotainment General automotive Electronic appliances Power Grid / Smart meter / appliances Industrial machines Computing • GPS electronic HEV/EV Solar / Wind inverters Building · Wireless charging · Connected car · Mining, oil, gas Charging station Solar / Wind power Power supplies · Autonomous driving DC distribution power generation • PFC • EMI/EMC • Inverter / motor drives • Shipping/Rail Converter storage Adaptive cruise control • UPS Radar test applications GaN / SiC SiC GaN



Devices: GaN/SiC Power Electronics – Superior Performance



Smaller

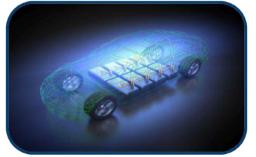
Energy Saving

Less Heat



Light Weight





Electric Vehicles



EV-charging



Data Centers



Renewable Energy



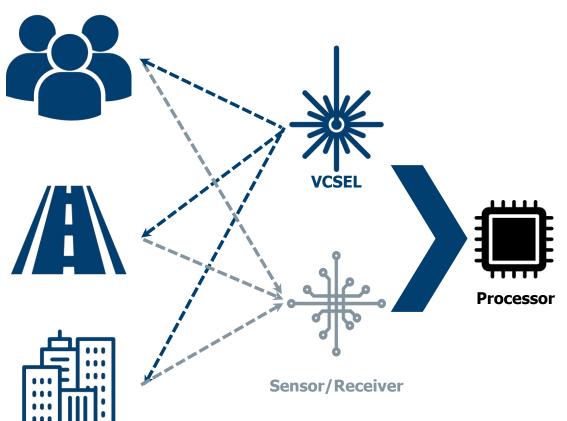


Fast Charging



Devices: VCSEL – Internet of Things Creates New Opportunities

3D Sensing Functionality





Facial Recognition



Autonomous Driving



Tailor-made clothing/shoes



Interior Design



Mapping

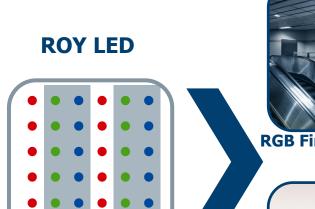


Industry 4.0



Devices: ROY LEDs for RGB Displays; UV LEDs for Niche Markets





RGB Fine-Pitch Indoor Display (Pixel Pitch ≤2.5mm)

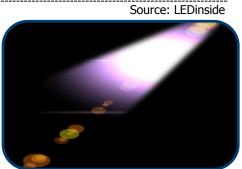


RGB Stadium Outdoor Display (Pixel Pitch ≥10mm)

UV LED







Curing



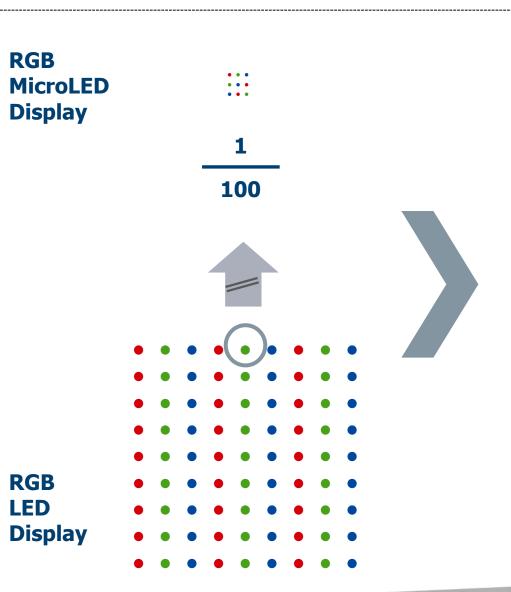
Water Disinfection



Air Purifier



Devices: MicroLED – The Perfect Future Display Technology



Self-Emissive

Low Power Consumption

Perfect Contrast

High Brightness

Fast Response



Wearables



AR/VR



Signage



Smartphones/Tablets/TVs



INDUSTRY

AIXTRON Competitive Landscape

		USA	Europe	China	Korea	Japan
Compound	GaAs/InP Optoelectronics, ROY LED	Veeco				TAIYO NIPPON SANSO The Gas Professionals
	GaN LED	Veeco		TOPEC		TAIYO NIPPON SANSO The Gas Professionals
	GaN Power	Veeco				TAIYO NIPPON SANSO The Gas Professionals
	SiC Power		L PE			TOKYO ELECTRON NUFLARE
Silicon					WONIK IPS	TOKYO ELECTRON Hitachi Kokusai Electric Inc.
Organics		APPLIED MATERIALS			WONK IPS SFA AP Systems SEA AP Systems	CATIOTI CANON TOKKI CORPORATION ULVAC



APEVA SE Partner TFE Frozen 26

Organic Electronics – OVPD® – APEVA SE

Source: DisplaySearch, AIXTRON **OLED manufacturing process** Cleaning Cleaning **Glass cutting ITO deposition Organic material Bonding** deposition **Coating Etching Cathode deposition Aging Stripping Encapsulation Final test** (Thin film; TFE) **Test and repair** Front-end **Front-end Back-end Cell process equipment Array process equipment Module process equipment RIXTRUM** Targeted technology



APEVA SE Partner

Organic Electronics - OVPD® - APEVA SE

Product Description – OVPD

- Proprietary carrier-gas enhanced gas phase deposition approach for organic thin films
- Based on AIXTRON's core competence of carrier gas enhanced vapor phase deposition
- Free scalability: suitable for all relevant substrate generations
- Manufacturing technology applicable for OLED displays, OLED lighting, organic semiconductors, and organic photovoltaic
- Proprietary STExS[™] evaporation source technology: low thermal stress, high rates, continuous operation

"Disruptive deposition technology for cost efficient OLED manufacturing"

Product Features

- High deposition rates for high throughput
- Reduced thermal stress for organic materials
- High material utilization efficiency
- Flexible process control
- Simplified scaling due to
 - Close Coupled Showerhead and
 - Decoupled source technology
- Flexible integration solutions batch and inline
- Reduced number of deposition chamber and footprint
- Scalable: Available for substrate sizes up to Gen8.5 (=2.3 x 2.5 m²)



OVPD demonstrator OLAD (Organic Large Area Demonstrator) (optimized for Generation 8.5 substrate sizes)



NANO Innovation Pool

Carbon Nanomaterials – PECVD

Graphene and Carbon Nanotube Deposition Systems

- Proprietary thermal and plasma enhanced chemical vapor deposition technology
- Excellent uniformity and reproducibility with fast turnaround cycle times
- BM platform: BM R&D (2-inch), BM Pro (4-inch and 6-inch), BM GB (4-inch glovebox), BM HT (high temperature, 1,700C), BM300T (300mm)
- Graphene and carbon nanotube films for electronics, energy storage, thermal management, sensors and flexible/transparent applications

Product features

- Fast response heater and turnaround
- Thermal CVD
- Substrate and top heating
- Closed loop infrared wafer temperature control
- Plasma enhanced CVD with frequency control
- Flexible processing for different applications
- Low cost of ownership
- Easy maintenance and cleaning
- User management features and growth library

Material Properties



AIXTRON Technology



Enabling Applications



Graphene (2D) and Carbon nanotube (1D)

Unique combination of high electrical/ thermal conductivity, mobility, flexibility and transparency



Serving R&D market today
AIXTRON BM Pro



Production ready for tomorrow AIXTRON BM Pro 300



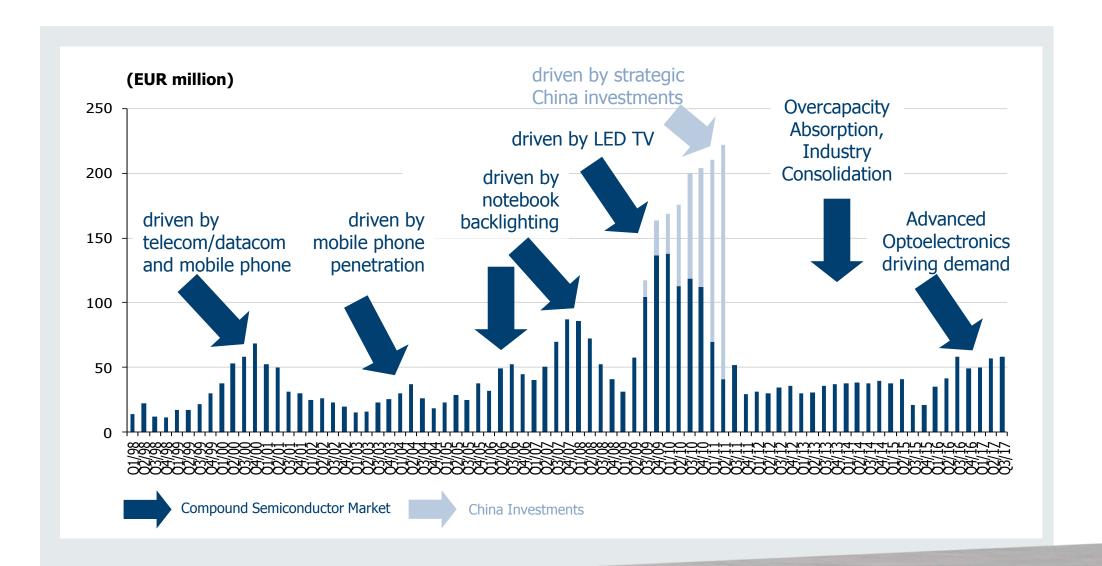
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Our technology. YOUR FUTURE.



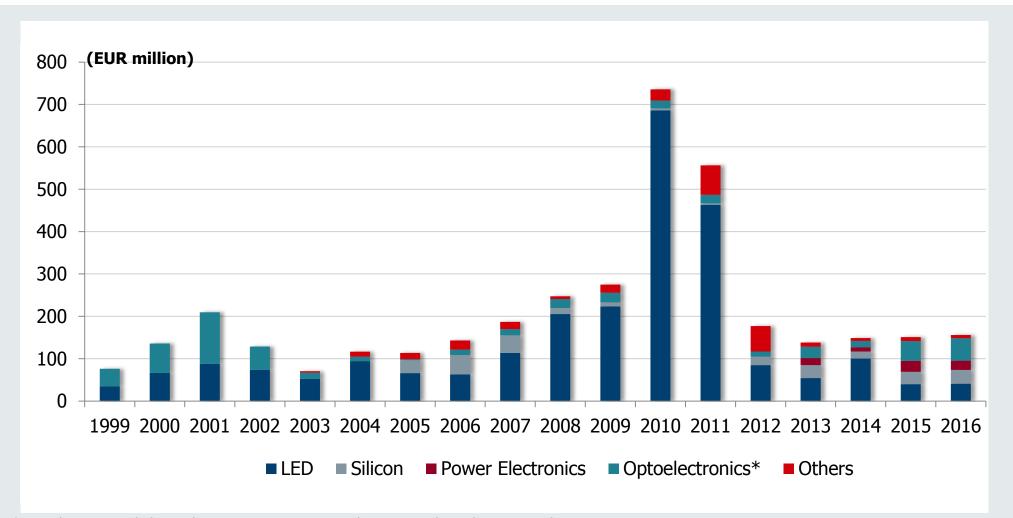
OPERATIONS

Equipment Order Intake per Quarter





Annual Equipment Revenues by Application (excl. spares)



^{*} Optoelectronics includes applications in Consumer Optoelectronics, Telecom/Datacom, Solar, etc.



Consolidated Income Statement*

(€ million)	2016	2015	2014
Revenues	196.5	197.8	193.8
Cost of sales	140.2	147.9	154.1**
Gross profit	56.3	49.8	39.7**
%	29%	<i>25</i> %	20 /
Selling expenses	13.8	11.5	14.1**
General & admin expenses	17.1	16.3	19.3
R&D	53.9	55.4	66.7
Net other operating income & expenses	-7.2	-6.7	-2.2
EBIT	-21.4	-26.7	-58.3
%	-11%	-14%	-30%
Result before tax	-21.0	-26.0	-57.1
%	-11%	-13%	-29 //
Net result	-24.0	-29.2	-62.5
%	-12%	-15%	-32 %



^{**) 2014} figures adjusted to be comparable

Balance Sheet*

(€ million)	31/12/16	31/12/15	31/12/14
Property, plant & equipment	74.2	81.3	77.3
Goodwill	74.6	75.9	64.8
Other intangible assets	5.4	6.4	2.5
Others	2.4	3.9	4.6
Non-current assets	156.5	167.6	149.2
Inventories, WIP & Finished Goods	54.2	70.8	81.7
Trade receivables	60.2	26.0	26.3
Others	5.3	8.2	8.3
Cash & Cash Equivalents incl. CD	160.1	209.4	268.1
Current Assets	279.7	314.4	384.4
Shareholders' equity	369.7	396.5	415.7
Non-current liabilities	4.2	3.6	1.3
Trade payables	14.6	9.8	16.4
Advance payments from customers	26.1	24.0	66.9
Others	21.6	48.0	33.2
Current liabilities	62.3	81.8	116.5
Balance Sheet total	436.2	482.0	533.5



Consolidated Statement of Cash Flows*

(€ million)	2016	2015	2014
Cash Flow from operating activities	-37.7	-45.7	-33.8
Cash Flow from investing activities	43.4	41.2	-23.2
Cash Flow from financing activities	0.3	-0.1	0.2
Exchange rate changes	-2.3	4.3	5.9
Net change in Cash & Cash Equivalents	3.7	-0.3	-50.9
Cash & Cash Equivalents (beginning of period)	116.3	116.6	167.5
Cash & Cash Equivalents (end of period)	120.0	116.3	116.6
Change in Cash deposits	-52.8	-60.5	9.9
Free Cash Flow**	-42.9	-57.3	-47.0
Capex	5.3	13.3	13.4



^{**)} Operating CF + Investing CF + Changes in Cash Deposits, adjusted for acquisition effects

Financial Calendar & Contact Data

•	February	27, 2018	FY/2017 Results, Conference Call
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- April 26, 2018 Q1/2018 Results, Conference Call
- May 16, 2018
 2018 Annual General Meeting, Aachen, Germany
- July 26, 2018 Q2/2018 Results, Conference Call
- October 30, 2018 Q3/2018 Results, Conference Call

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Technology. Materials. Performance.

